INTEGRATED CIRCUITS

DATA SHEET

74F543

Octal registered transceiver, non-inverting (3-State)

Product data sheet Replaces data sheet 74F543/74F544 of 1994 Dec 05





Octal registered transceiver, non-inverting (3-State)

74F543

FEATURES

- Combines74F245 and 74F373 type functions in one chip
- 8-bit octal transceiver with D-type latch
- Back-to-back registers for storage
- Separate controls for data flow in each direction
- A outputs sink 20 mA and source 3 mA
- B outputs sink 64 mA and source 15 mA
- 3-State outputs for bus-oriented applications
- Available in SSOP Type II package

DESCRIPTION

The 74F543 Octal Registered Transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable (LEAB, LEBA) and Output Enable (OEAB, OEBA) inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow. The A outputs are guaranteed to sink 24 mA, while the B outputs are rated for 64 mA.

FUNCTIONAL DESCRIPTION

The 74F543 contains two sets of eight D-type latches, with separate input and controls for each set. For data flow from A to B, for example, the A-to-B Enable (EAB) input must be LOW in order to enter data from A0 - A7 or take data from B0 - B7, as indicated in the Function Table. With EAB LOW, a LOW signal on the A-to-B Latch Enable (LEAB) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition for the LEAB signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With EAB and OEAB both LOW, the 3-State B output buffers are active and display the data present at the outputs of the A latches. Control of data flow from B to A is similar, but using the EBA, LEBA, and OEBA inputs.

	TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
ſ	74F543	6.0 ns	80 mA

ORDERING INFORMATION

Commerical range: V_{CC} = 5 V ± 10 %; T_{amb} = 0 °C to +70 °C

Type number	Package									
	Name	Description	Version							
N74F543D	SO24	plastic small outline package; 24 leads; body width 7.5 mm	SOT137-1							
N74F543DB	SSOP24	plastic shrink small outline pacakge; 24 leads; body width 5.3 mm	SOT340-1							
N74F543N	DIP24	plastic dual in-line package; 24 leads (300 mil)	SOT222-1							

INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

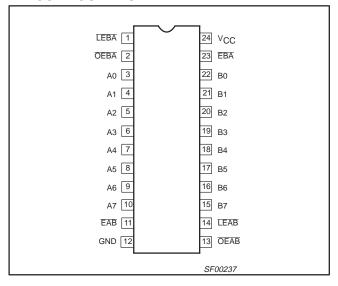
PINS	DESCRIPTION	74F(U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW		
A0 - A7	Port A, 3-State inputs	3.5/1.0	70 μA/0.6 mA		
B0 - B7	Port B, 3-State inputs	3.5/1.0	70 μA/0.6 mA		
OEAB A-to-B Output Enable input (Active LOW)		1.0/1.0	20 μA/0.6 mA		
OEBA	B-to-A Output Enable input (Active LOW)	1.0/1.0	20 μA/0.6 mA		
EAB	A-to-B Enable input (Active LOW)	1.0/2.0	20 μA/1.2 mA		
EBA	B-to-A Enable input (Active LOW)	1.0/2.0	20 μA/1.2 mA		
LEAB	A-to-B Latch Enable input (Active LOW)	1.0/1.0	20 μA/0.6 mA		
LEBA	B-to-A Latch Enable input (Active LOW)	1.0/1.0	20 μA/0.6 mA		
A0 - A7	Port A, 3-State outputs	150/40	3.0 mA/24 mA		
B0 - B7	Port B, 3-State outputs	750/106.7	15 mA/64 mA		

NOTE: One (1.0) FAST Unit Load is defined as: $20~\mu A$ in the HIGH State and 0.6mA in the LOW state.

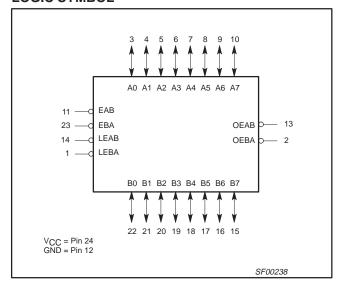
Octal registered transceiver, non-inverting (3-State)

74F543

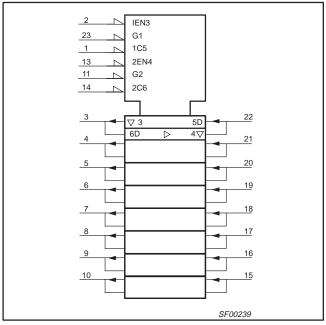
PIN CONFIGURATION



LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE for 74F543

	INP	UTS			STATUS
OEXX	EXX	LEXX	DATA	OUTPUTS	
Н	Х	Х	Х	Z	Disabled
Х	Н	Х	Х	Z	Disabled
L	1	L	h	Z	Disable +
L	1	L	I	Z	Latch
L	L	↑	h	Н	Latch +
L	L	↑	- 1	L	Display
L	L	L	Н	Н	Transparent
L	L	L	L	L	mansparent
L	L	Н	Х	NC	Hold

H = HIGH voltage level

L = LOW voltage level

h = HIGH state must be present one setup time before the LOW-to-HIGH transition of LEXX or EXX (XX=AB or BA)

I = LOW state must be present one setup time before the LOW-to-HIGH transition of LEXX or EXX (XX=AB or BA)

 \uparrow = LOW-to-HIGH transition of \overline{LEXX} or \overline{EXX} XX = AB or BA

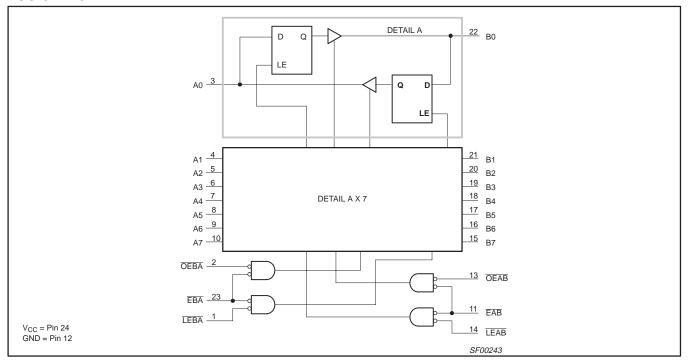
X = Don't care NC = No change

Z = High-impedance "off" state

Octal registered transceiver, non-inverting (3-State)

74F543

LOGIC DIAGRAM



Octal registered transceiver, non-inverting (3-State)

74F543

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limits set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER			RATING	UNIT		
V _{CC}	Supply voltage			-0.5 to +7.0	V		
V _{IN}	Input voltage			-0.5 to +7.0			
I _{IN}	Input current		-30 to +5	mA			
V _{OUT}	Voltage applied to output in HIGH output state	-0.5 to +5.5	V				
	Command applied to contract in 1 CMA contract state	A0 - A7		48	mA		
lout	Current applied to output in LOW output state		128	mA			
T _{amb}	Operating free-air temperature range			0 to +70	°C		
T _{stg}	Storage temperature		-65 to +150	°C			

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER			UNIT		
STIVIBUL	PARAMETER		MIN	NOM	MAX	UNII
V _{CC}	Supply voltage		4.5	5.0	5.5	V
V _{IH}	HIGH-level input voltage		2.0	_	_	V
V _{IL}	LOW-level input voltage	_	-	0.8	V	
I _{IK}	Input clamp current	_	-	-18	mA	
	LHCH level systems suggest	A0 - A7	_	-	-3	mA
ІОН	HIGH-level output current	B0 - B7	_	-	-15	mA
	LOW level extent extent	A0 - A7	-	-	24	mA
loL	LOW-level output current	_	-	64	mA	
T _{amb}	Operating free-air temperature range		-0	-	+70	°C

Octal registered transceiver, non-inverting (3-State)

74F543

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

SYMBOL	DADAMETE	. D		ıe1		LIMITS		UNIT	
STWBUL	PARAMETE	:K	"	EST CONDITION	19,	MIN	TYP ²	MAX	UNII
	HIGH-level output voltage	A0 - A7	.,	1 2 m A	± 10 % V _{CC}	2.4	_	_	V
\ /		AU - A7	$V_{CC} = MIN$ $V_{IL} = MAX$	$I_{OH} = -3 \text{ mA}$	± 5 % V _{CC}	2.7	3.4	-	V
V_{OH}		B0 - B7	$V_{IH} = MIN$	1 - 15 m	± 10 % V _{CC}	2.0	_	_	V
		B0 - B7	VIII	$I_{OH} = -15 \text{ mA}$	± 5 % V _{CC}	2.0	_	_	V
		A0 - A7		1 - 24 mA	± 10 % V _{CC}	_	0.35	0.50	V
V	LOW-level output voltage	AU - A7	$V_{CC} = MIN$	I _{OL} = 24 mA	± 5 % V _{CC}	_	0.35	0.50	V
V _{OL}		B0 - B7	$V_{IL} = MAX$ $V_{IH} = MIN$	L 64 m A	± 10 % V _{CC}	_	_	0.55	٧
		BU - B7		$I_{OL} = 64 \text{ mA}$	± 5 % V _{CC}	_	0.42	0.55	V
V _{IK}	Input clamp voltage		$V_{CC} = MIN; I_I = I_{IK}$				-0.73	-1.2	V
	Input current at maximum	OEAB, OEBA, EAB	$V_{CC} = MAX;$	V _I = 7.0 V		_	_	100	μΑ
t _l	input voltage	Others	$V_{CC} = 5.5 V;$	V _I = 5.5 V		_	_	1	mA
I _{IH}	HIGH-level input current		$V_{CC} = MAX;$	V _I = 2.7 V		_	_	20	μΑ
	LOW-level input current	Others	\/ _ MAV.	_	_	-0.6	mA		
I _{IL}	LOvv-level input current	EAB, EBA	$V_{CC} = MAX;$		_	_	-1.2	mA	
I _{OZH} + I _{IH}	Off-state output current, HIGH-	level voltage applied	V _{CC} = MAX; \	V _O = 2.7 V		_	_	70	μΑ
I _{OZH} + I _{IL}	Off-state output current, LOW-l	evel voltage applied	V _{CC} = MAX;	V _O = 0. 5 V		_	_	-600	μΑ
	Short-circuit output current ³	A0 - A7	\/ MAAV			-60	_	-150	mA
los	Short-circuit output currents	B0 - B7	$V_{CC} = MAX$			-100	_	-225	mA
		Іссн				_	70	105	mA
I_{CC}	Supply current (total)	I _{CCL}	$V_{CC} = MAX$				95	135	mA
		I _{CCZ}				-	95	135	mA

^{1.} For conditions shown as MIN or MAX, use the appropriate value specified under the recommended operating conditions for the applicable

All typical values are at V_{CC} = 5 V, T_{amb} = 25 °C. Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a HIGH output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, IOS tests should be performed last.

Octal registered transceiver, non-inverting (3-State)

74F543

AC ELECTRICAL CHARACTERISTICS

					LIM	ITS		
SYMBOL	PARAMETER	TEST CONDITIONS	١ ١	_{lmb} = +25 ^o / _{CC} = 5.0 \ 0 pF; R _L =	/	T _{amb} = 0 °C V _{CC} = 5.0 C _L = 50pF;	UNIT	
			MIN	TYP	MAX	MIN	MAX	
t _{PLH}	Propagation delay A _n to B _n	Waveform 1	3.5 3.0	5.5 5.0	8.5 8.0	3.0 2.5	9.0 8.5	ns
t _{PLH} t _{PHL}	Propagation delay B _n to A _n	Waveform 1	2.5 2.5	4.0 4.5	7.0 7.5	2.5 2.5	7.5 8.0	ns
t _{PLH} t _{PHL}	Propagation delay LEBA to A _n	Waveform 1	5.0 4.0	7.0 6.0	10.0 9.0	4.5 4.0	11.0 9.5	ns
t _{PLH} t _{PHL}	Propagation delay LEAB to B _n	Waveform 1	6.0 4.5	8.5 6.5	11.5 9.5	5.5 4.0	12.5 10.0	ns
t _{PZH}	Output Enable time OEBA to A _n or OEAB to B _n	Waveform 3 Waveform 4	2.0 3.5	4.0 5.0	7.5 8.5	1.5 3.0	8.0 9.0	ns
t _{PHZ}	Output Disable time OEBA to A _n or OEAB to B _n	Waveform 3 Waveform 4	1.0 1.5	3.0 4.0	6.5 7.5	1.0 1.0	7.5 8.5	ns
t _{PZH}	Output Enable time EBA to A _n or EAB to B _n	Waveform 3 Waveform 4	4.5 5.0	7.0 7.0	10.5 10.5	4.0 4.5	11.5 11.0	ns
t _{PHZ} t _{PLZ}	Output Disable time EBA to A _n or EAB to B _n	Waveform 3 Waveform 4	2.5 4.5	5.0 7.0	8.5 11.0	2.0 3.0	9.5 12.0	ns

AC SETUP REQUIREMENTS

SYMBOL	PARAMETER	TEST CONDITIONS	$T_{amb} = V_{CC} = C_L = 50 pF;$	5.0 V	$T_{amb} = 0 ° C$ $V_{CC} = 5.0$ $C_L = 50 pF;$	UNIT		
			MIN	TYP	MIN	MAX		
t _s (H) t _s (L)	Setup time, HIGH or LOW A_n to \overline{LEAB} or B_n to \overline{LEBA}	Waveform 2	0.0 2.5	<u> </u>	0.0 3.0	_ _	ns	
t _h (H) t _h (L)	Hold time, HIGH or LOW A _n to LEAB or B _n to LEBA	Waveform 2	0.0 1.5	_ _	0.0 2.0	- -	ns	
t _s (H) t _s (L)	Setup time, HIGH or LOW A _n to EAB or B _n to EBA	Waveform 2	1.0 2.5	_ _	1.5 3.0	- -	ns	
t _h (H) t _h (L)	Hold time, HIGH or LOW A _n to EAB or B _n to EBA	Waveform 2	0.0 1.5	- -	0.0 2.0	_ _ _	ns	
t _w (L)	Latch enable pulse width, LOW	Waveform 2	4.0	_	4.5	_	ns	

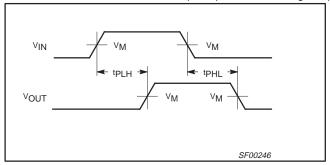
Octal registered transceiver, non-inverting (3-State)

74F543

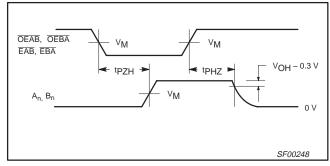
AC WAVEFORMS

 $V_{M} = 1.5 V$.

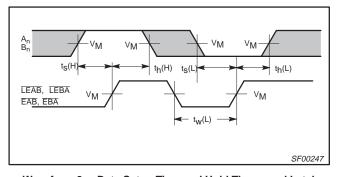
The shaded areas indicate when the input is permitted to change for predictable output performance.



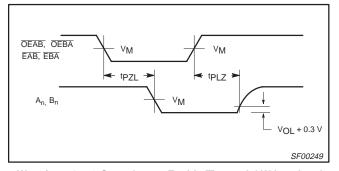
Waveform 1. Propagation delay for non-inverting outputs



Waveform 3. 3-State Output Enable Time to HIGH Level and Output Disable Time from HIGH Level

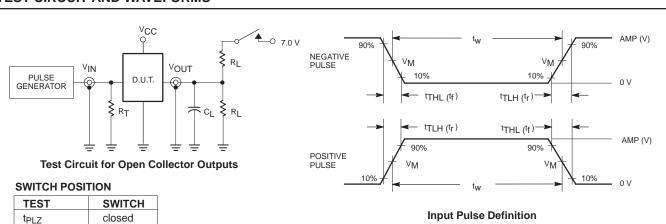


Waveform 2. Data Setup Time and Hold Times, and Latch Enable Pulse Width



Waveform 4. 3-State Output Enable Time to LOW Level and Output Disable Time from LOW Level

TEST CIRCUIT AND WAVEFORMS



DEFINITIONS:

t_{PZL} All other

 R_L = Load resistor;

see AC electrical characteristics for value.

closed

open

C_L = Load capacitance includes jig and probe capacitance; see AC electrical characteristics for value.

 R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

family	INPUT PULSE REQUIREMENTS										
laililly	amplitude	V_{M}	rep. rate	t _w	t _{TLH}	t _{THL}					
74F	3.0 V	1.5 V	1 MHz	500 ns	2.5 ns	2.5 ns					

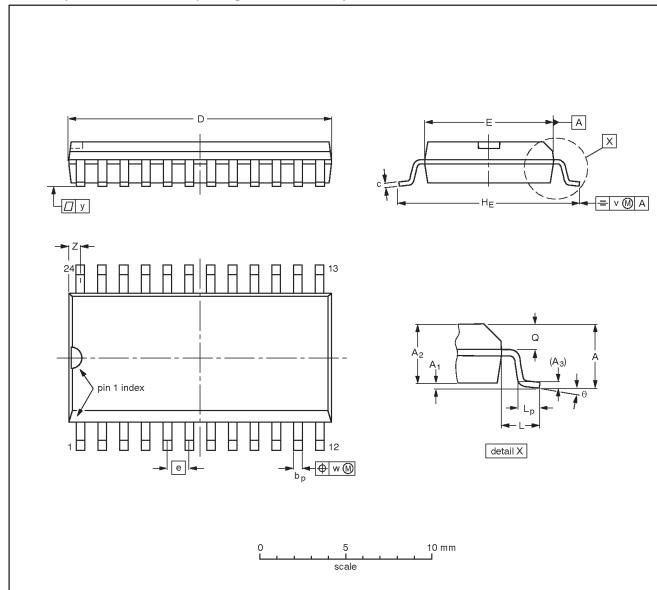
SF00128

Octal registered transceiver, non-inverting (3-State)

74F543

SO24: plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	٧	w	у	z ⁽¹⁾	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	15.6 15.2	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	ı	0.01	0.019 0.014	0.013 0.009	0.61 0.60	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

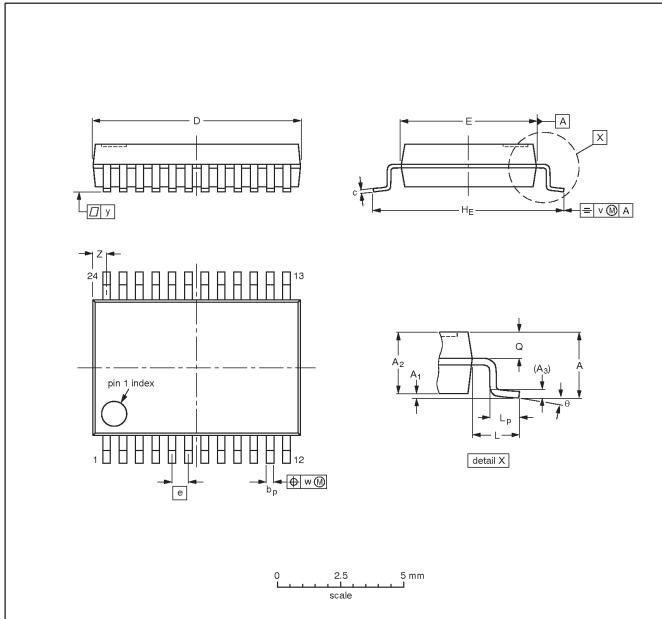
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT137-1	075E05	MS-013				-99-12-27 03-02-19	

Octal registered transceiver, non-inverting (3-State)

74F543

SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm

SOT340-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	8.4 8.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.8 0.4	8° 0°

Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

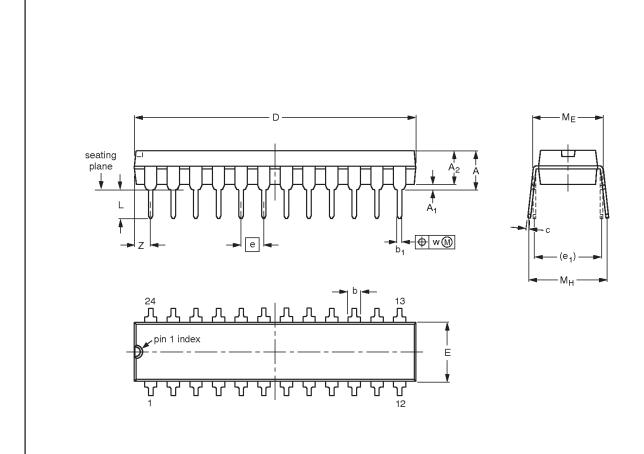
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA	PROJECTION		ISSUE DATE	
SOT340-1		MO-150				99-12-27 03-02-19	

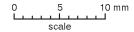
Octal registered transceiver, non-inverting (3-State)

74F543

DIP24: plastic dual in-line package; 24 leads (300 mil)

SOT222-1





DIMENSIONS (mm dimensions are derived from the original inch dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E (1)	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.7	0.38	3.94	1.63 1.14	0.56 0.43	0.36 0.25	31.9 31.5	6.73 6.25	2.54	7.62	3.51 3.05	8.13 7.62	10.03 7.62	0.25	2.05
inches	0.185	0.015	0.155	0.064 0.045	0.022 0.017	0.014 0.010	1.256 1.240	0.265 0.246	0.1	0.3	0.138 0.120	0.32 0.30	0.395 0.300	0.01	0.081

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	1990E DATE	
SOT222-1		MS-001				99-12-27 03-03-12	

Octal registered transceiver, non-inverting (3-State)

74F543

REVISION HISTORY

Rev	Date	Description
_3	20040722	Product data sheet (9397 750 13803). Replaces Product specification 74F543_544_1 of 1994 Dec 05 (9397 750 05135).
		Modifications:
		● Remove part-type 74F544 and all its references.
		● Change Type number for SSOP24 package from "74F543DB" to "N74F543DB".
_2	19941205	Product specification (9397 750 05135). ECN 853-0874 14379 of 05 December 1994.

Data sheet status

Level	Data sheet status [1]	Product status ^[2] [3]	Definitions
I	Objective data sheet	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data sheet	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data sheet	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

^[1] Please consult the most recently issued data sheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Disclaimers

Life support — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes in the products—including circuits, standard cells, and/or software—described or contained herein in order to improve design and/or performance. When the product is in full production (status 'Production'), relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Contact information

For additional information please visit

http://www.semiconductors.philips.com. Fax: +31 40 27 24825

For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com

© Koninklijke Philips Electronics N.V. 2004 All rights reserved. Printed in U.S.A.

Date of release: 07-04

Document order number: 9397 750 13803

Let's make things better.

Philips Semiconductors





^[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

^[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.